

# HAT2132H

Silicon N Channel MOS FET  
High Speed Power Switching

REJ03G0177-0300

Rev.3.00

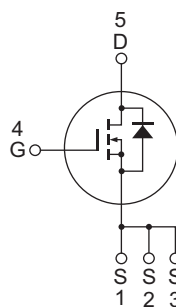
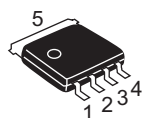
Dec 07, 2006

## Features

- Low drive current.
- Low on-resistance
- Low profile

## Outline

RENESAS Package code: PTZZ0005DA-A  
(Package name: LFPAK )



1, 2, 3 Source  
4 Gate  
5 Drain

## Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	200	V
Gate to source voltage	$V_{GSS}$	±30	V
Drain current	$I_D$	6	A
Drain peak current	$I_{D(pulse)}$ <sup>Note1</sup>	24	A
Body-drain diode reverse drain current	$I_{DR}$	6	A
Body-drain diode reverse drain peak current	$I_{DR(pulse)}$ <sup>Note1</sup>	24	A
Avalanche current	$I_{AP}$ <sup>Note3</sup>	6	A
Avalanche energy	$E_{AR}$ <sup>Note3</sup>	2.4	mJ
Channel dissipation	$P_{ch}$ <sup>Note2</sup>	20	W
Channel to case thermal impedance	$\theta_{ch-c}$	6.25	°C/W
Channel temperature	$T_{ch}$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

Notes: 1.  $PW \leq 10 \mu s$ , duty cycle  $\leq 1\%$

2. Value at  $T_c = 25^\circ C$

3.  $STch = 25^\circ C$ ,  $T_{ch} \leq 150^\circ C$

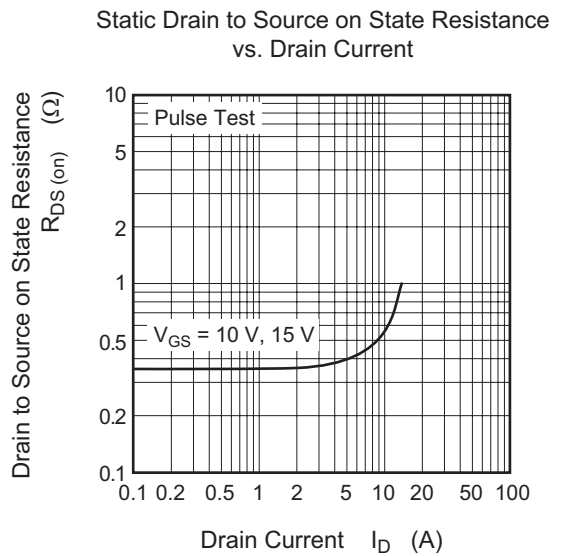
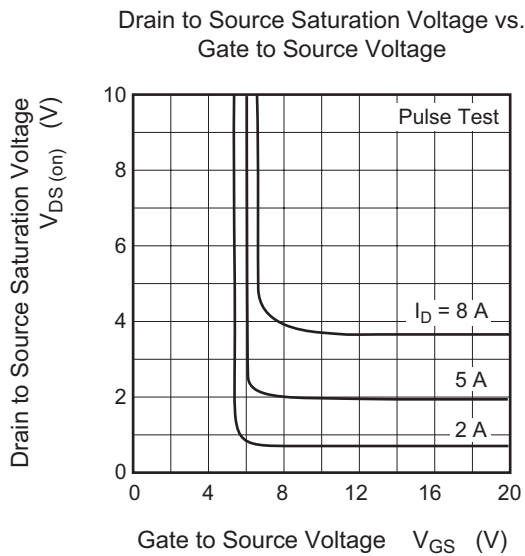
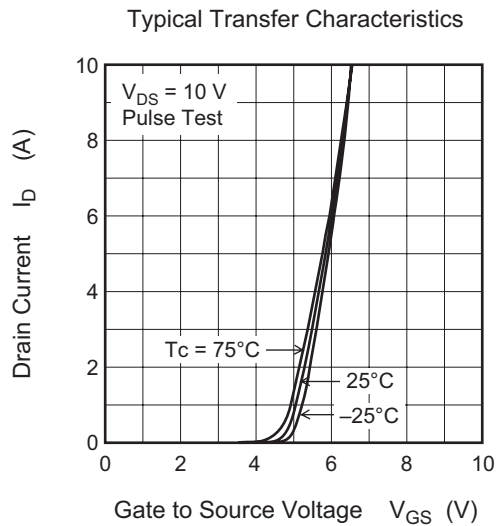
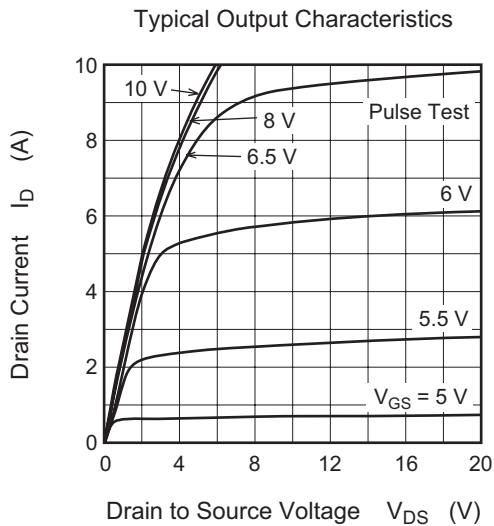
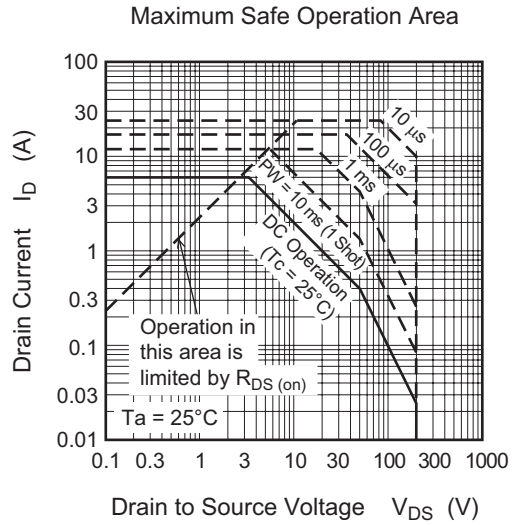
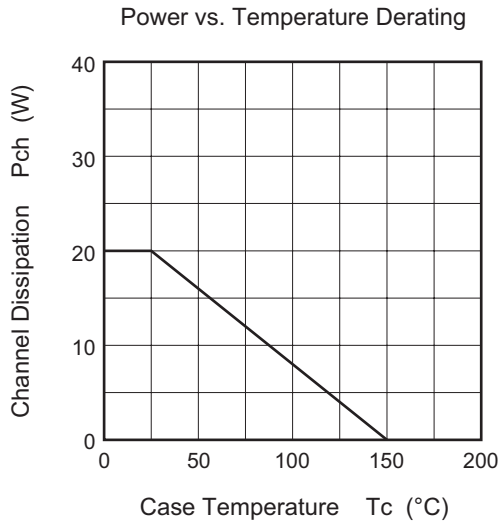
## Electrical Characteristics

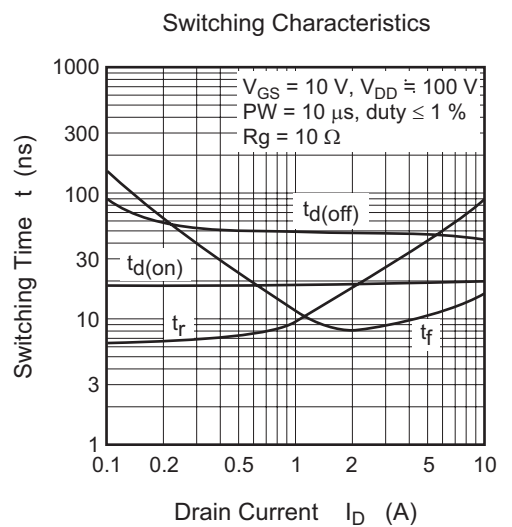
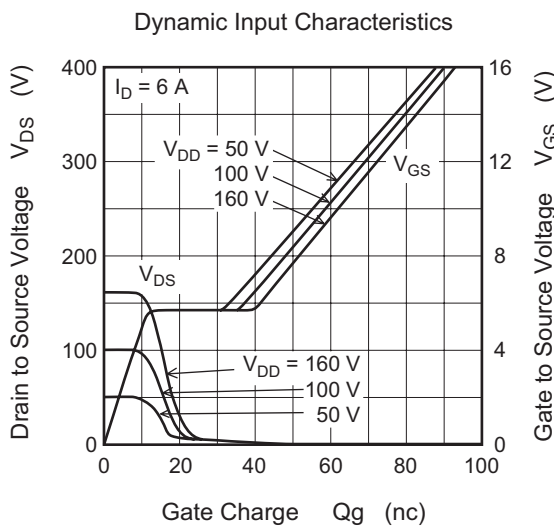
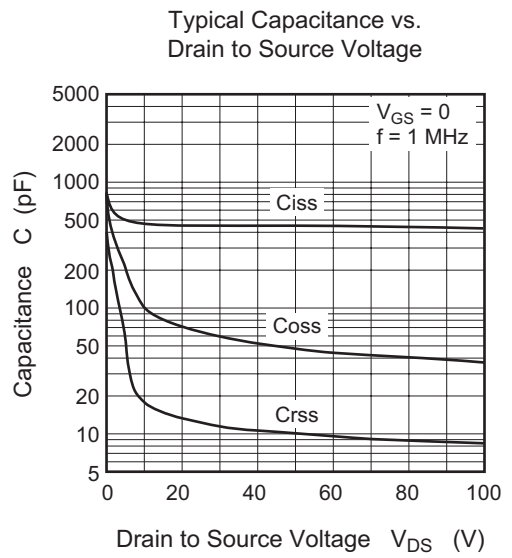
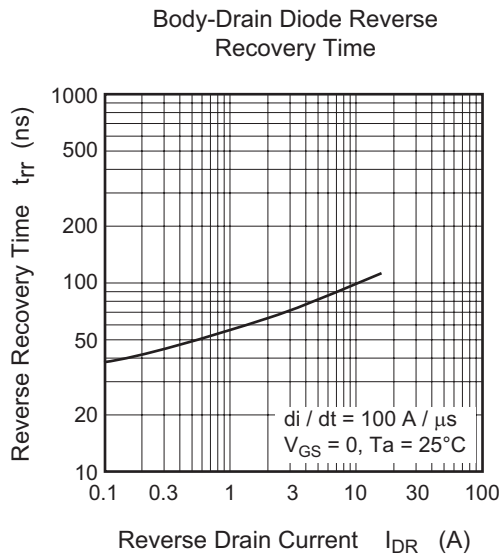
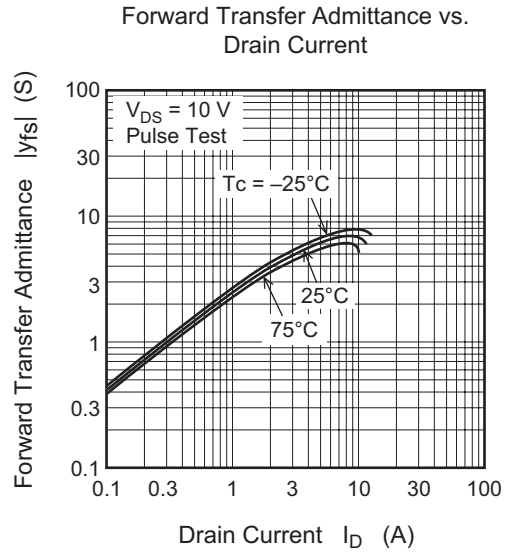
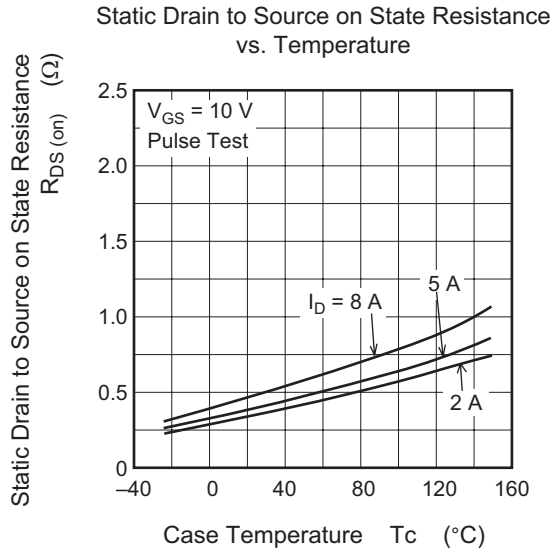
(Ta = 25°C)

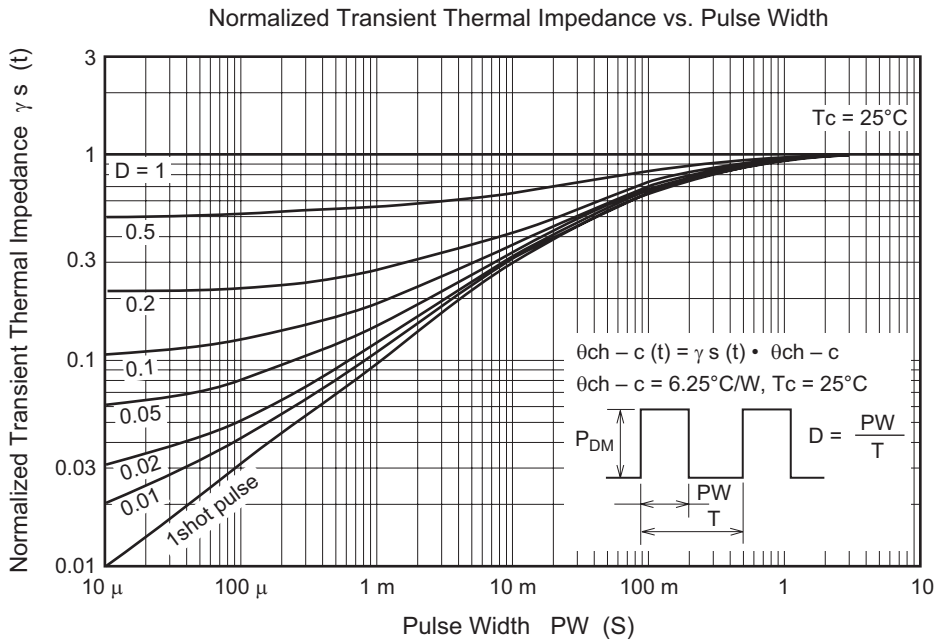
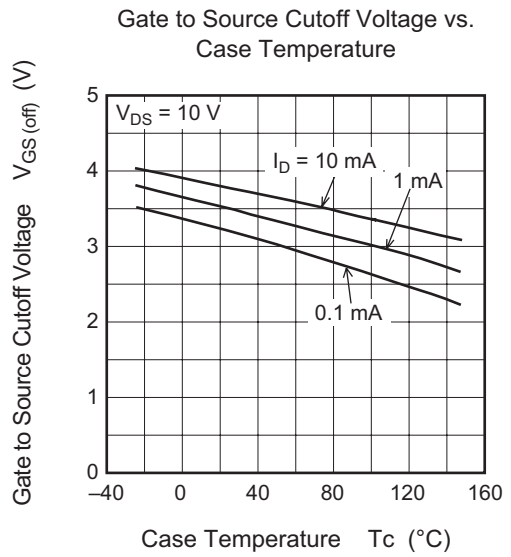
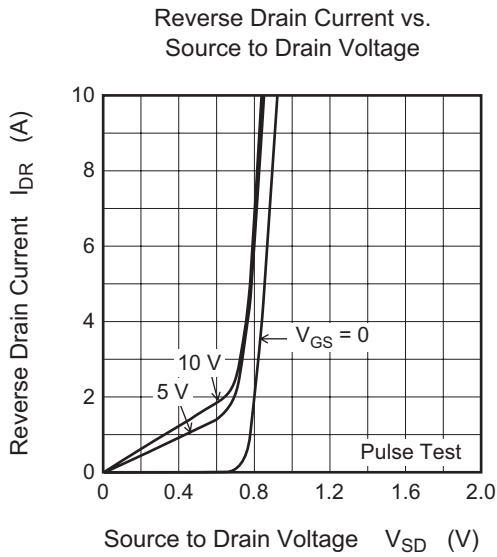
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	200	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 200 \text{ V}$ , $V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 0.1$	$\mu\text{A}$	$V_{GS} = \pm 30 \text{ V}$ , $V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3.0	—	4.0	V	$V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$
Forward transfer admittance	$ y_{fs} $	2.7	4.7	—	S	$I_D = 3 \text{ A}$ , $V_{DS} = 10 \text{ V}$ <sup>Note4</sup>
Static drain to source on state resistance	$R_{DS(on)}$	—	0.36	0.45	$\Omega$	$I_D = 3 \text{ A}$ , $V_{GS} = 10 \text{ V}$ <sup>Note4</sup>
Input capacitance	$C_{iss}$	—	450	—	pF	$V_{DS} = 25 \text{ V}$
Output capacitance	$C_{oss}$	—	65	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	$C_{rss}$	—	13	—	pF	$f = 1 \text{ MHz}$
Turn-on delay time	$t_{d(on)}$	—	19	—	ns	$I_D = 3 \text{ A}$
Rise time	$t_r$	—	26	—	ns	$V_{GS} = 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	48	—	ns	$R_L = 33.3 \Omega$
Fall time	$t_f$	—	9	—	ns	$R_g = 10 \Omega$
Total gate charge	$Q_g$	—	12.5	—	nC	$V_{DD} = 160 \text{ V}$
Gate to source charge	$Q_{gs}$	—	2.5	—	nC	$V_{GS} = 10 \text{ V}$
Gate to drain charge	$Q_{gd}$	—	6	—	nC	$I_D = 6 \text{ A}$
Body-drain diode forward voltage	$V_{DF}$	—	0.85	1.30	V	$I_F = 6 \text{ A}$ , $V_{GS} = 0$ <sup>Note4</sup>
Body-drain diode reverse recovery time	$t_{rr}$	—	95	—	ns	$I_F = 6 \text{ A}$ , $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

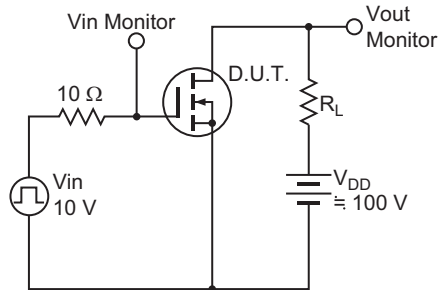
### Main Characteristics



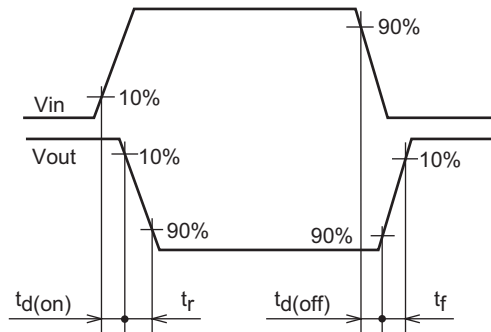




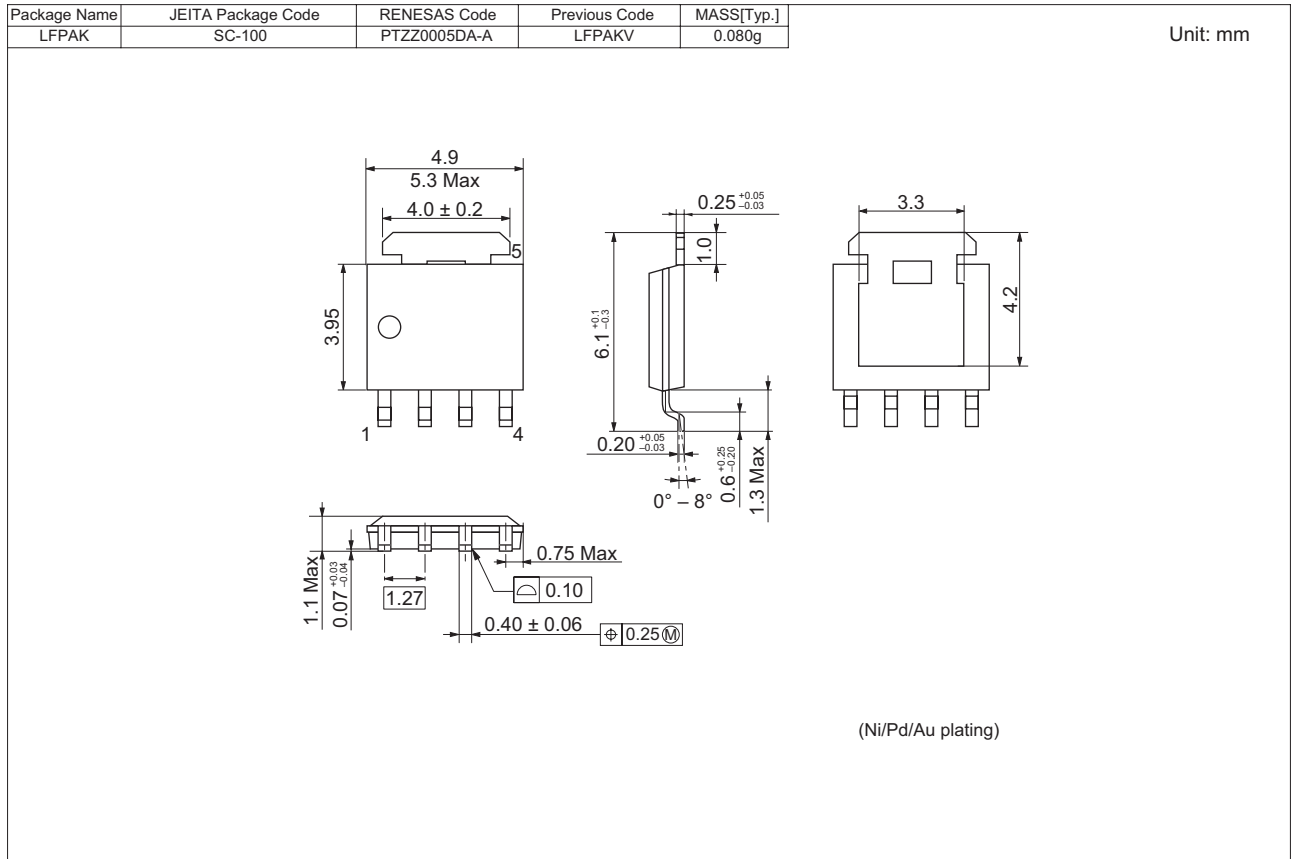
Switching Time Test Circuit



Switching Time Waveform



Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
HAT2132H-EL-E	2500 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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